

A model of transport nonuniversality in thick-film resistors

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We propose a model of transport in thick-film resistors which naturally explains the observed nonuniversal values of the conductance exponent t extracted in the vicinity of the percolation transition. Essential ingredients of the model are the segregated microstructure typical of thick-film resistors and tunneling between the conducting grains. Nonuniversality sets in as consequence of wide distribution of interparticle tunneling distances.

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Thick-film resistors (TFRs) are glass-conductor composites based on RuO_2 (but also $\text{Bi}_2\text{Ru}_2\text{O}_7$, $\text{Pb}_2\text{Ru}_2\text{O}_6$, and IrO_2) grains mixed and fired with glass powders.¹ Besides the widespread use of TFRs in pressure and force sensor applications,² their transport properties are of great interest also for basic research. The percolating nature of transport in TFRs has been reported since long time and now it is well documented.³⁻⁹ As shown in Fig.1 where we reports a selection of previously published data on different TFRs,⁵⁻⁸ the conducting phase concentration x dependence of the conductance G of TFRs follows a percolating-like power-law equation of the form:

$$G = G_0(x - x_c)^t, \quad (1)$$

where G_0 is a prefactor, x_c is the critical concentration below which G vanishes and t is the transport critical exponent.^{10,11} The values of G_0 , x_c , and t which best fit the experimental data are reported in the inset of Fig.1.

According to the standard theory of transport in isotropic percolating systems,¹¹ G_0 and x_c depend on microscopic details such as the microstructure and the mean value of the junction resistances connecting two neighbouring conducting sites, while, unless the microscopic resistances have a diverging distribution function (see below), the critical exponent t is *universal*, i. e., it depends only upon the lattice dimensionality D . For $D = 3$, random resistor network calculations predict $t = t_0 \simeq 2.0$,¹² in agreement with various granular metal systems,^{13,14} or other disordered compounds.¹⁵

As it is clear from Fig.1, TFRs have values of t ranging from its universal limit $t \simeq 2.0$ (filled squares, Ref. 5) up to very high values like $t \sim 5.0$ (filled diamonds, Ref. 7) or even higher.³ Despite of their clear percolating

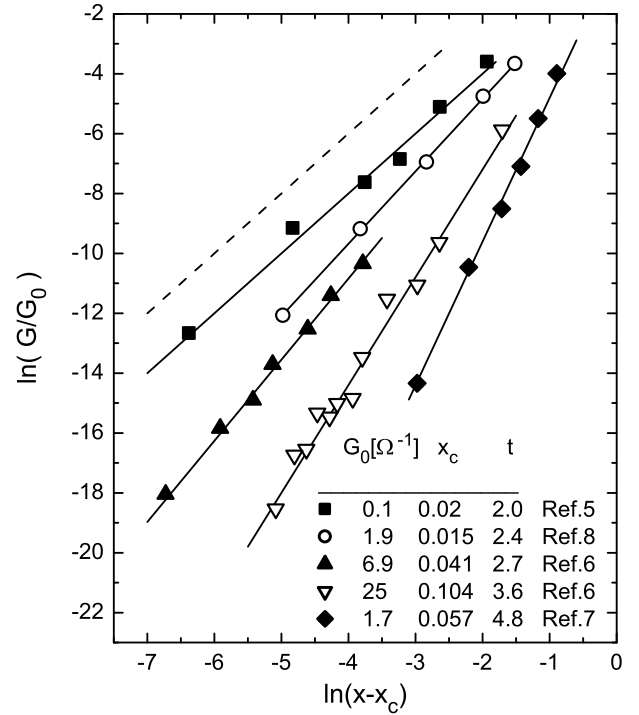


FIG. 1. Measured conductances on different RuO_2 (Refs. 6, 8) and $\text{Bi}_2\text{Ru}_2\text{O}_7$ (Refs. 5, 7) TFRs. Solid lines are fits to Eq.(1) with fitting values reported in the inset. dashed line denotes a power-law with exponent $t = 2$.

behavior, TFRs do not fulfil therefore the hypothesis of universality common to many systems and instead belong to a different, quite vast, class of materials which display nonuniversal transport behavior, that is a regime where the transport exponent t depends on microscopic details (microstructure etc.). Typical examples of nonuniversal systems are carbon-black-polymer composites,²⁰ and materials constituted by insulating regions embedded in a continuous conducting phase.^{14,16}

Despite that TFRs have been historically among the first materials for which transport nonuniversality has been reported,³ the microscopic origin of their universality breakdown has not been specifically addressed so far. In this letter we show that the cross-over between universality and nonuniversality reported in Fig.1 can be explained within a single model whose basic features are the peculiar microstructure of TFRs and the tunneling processes between conducting grains.

Before describing our model for TFRs, let us first recall the mathematical requisites for universality breakdown in random resistor networks. Consider a regular lattice of sites and assign to each neighbouring couple of sites a bond which has finite conductance g with probability p and zero conductance with probability $1-p$. The resulting conductance distribution function is then:

$$\rho(g) = ph(g) + (1-p)\delta(g), \quad (2)$$

where $\delta(g)$ is the Dirac delta-function and $h(g)$ is the distribution function of the finite bond conductances. For well behaved distribution functions $h(g)$, conductivity is universal and follows Eq.(1) with $t = t_0$. Instead, as first shown by Kogut and Straley,¹⁷ if $h(g)$ has a power law divergence for small g of the form:

$$\lim_{g \rightarrow 0} h(g) \propto g^{-\alpha}, \quad (3)$$

and α is larger than a critical value α_c , then transport is no longer universal. Renormalization group analysis predicts in fact that

$$t = \begin{cases} t_0 & \text{if } \nu + 1/(1-\alpha) < t_0 \\ \nu + 1/(1-\alpha) & \text{if } \nu + 1/(1-\alpha) > t_0 \end{cases}, \quad (4)$$

where $\nu \simeq 0.88$ is the correlation-length exponent for a three dimensional lattice.¹⁸ By using $t_0 \simeq 2.0$ we obtain therefore $\alpha_c \simeq 0.107$. Equations (3) and (4) have been shown to arise from a system of insulating spheres embedded in a continuous conducting material (swiss-cheese model),¹⁹ and from a tunneling-percolation model with highly fluctuating tunneling distances.²⁰ Here we show that Eq.(3) [and consequently Eq.(4)] arises naturally from a simple representation of TFRs in terms of their microstructure and elemental transport processes.

Let us start by considering the highly non-homogeneous microstructure typical of TFRs. These systems are constituted by a mixture of large glassy particles (typically with size L of order 1-3 μm) and small conducting grains of size Φ varying between ~ 10 nm up to ~ 200

nm. In this situation, the small metallic grains tend to occupy the narrow regions between the much larger insulating zones leading to a filamentary distribution of the conducting phase. A classical model to describe such a segregation effect was proposed already in the 1970's by Pike.³ This model treats the glassy particles as cubes of size $L \gg \Phi$ whose edges are occupied by chains of adjacent metallic spheres of diameter Φ . Such chains define channels (bonds) which form a cubic lattice spanning the whole sample. Let us assume for the moment that a bond has probability p of being occupied by a fixed number $n+1$ of spheres and probability $1-p$ of being empty. To each couple of adjacent spheres we assign an inter-sphere conductance σ_i ($i = 1, \dots, n$). A random resistor network can be therefore defined as in Eq.(2) where $h_n(g)$ is the distribution function of the total channel conductance g of n conductances σ_i in series:

$$g^{-1} = \sum_{i=1}^n \frac{1}{\sigma_i}. \quad (5)$$

The high values of piezoresistance (*i.e.*, the strain sensitivity of transport) typical of TFRs,¹ and the low temperature dependence of transport strongly indicate that the main contribution to the overall resistance stems from tunneling processes between neighbouring metallic grains. Hence, if the centers of two neighbouring metallic spheres are separated by a distance r , then the intergrain tunneling conductance σ is approximatively of the form:

$$\sigma = \sigma(r) \equiv \sigma_0 e^{-2(r-\Phi)/\xi}, \quad (6)$$

where σ_0 is a constant which we set equal to the unity, $\xi \propto 1/\sqrt{V}$ is the tunneling factor and V is the intergrain barrier potential. Let us make the quite general assumption that the centers of the spheres are set randomly along the channel, so that the distances r change according to the distribution function $P(r)$ for a set of impenetrable spheres arranged randomly in a quasi one dimensional channel. By following Ref.²¹, $P(r)$ can be calculated exactly and its explicit expression is:

$$P(r) = \frac{1}{a_n - \Phi} e^{-(r-\Phi)/(a_n-\Phi)} \Theta(r - \Phi) \quad (7)$$

where $a_n = (1 + L/n\Phi)\Phi/2$ is the mean inter-sphere distance and Θ is the step function. By combining Eq.(6) with Eq.(7) the distribution $f(\sigma)$ of the inter-sphere conductances is then:

$$f(\sigma) = \int_0^\infty dr P(r) \delta[\sigma - \sigma(r)] = (1 - \alpha_n) \sigma^{-\alpha_n}, \quad (8)$$

where

$$\alpha_n = 1 - \frac{\xi/2}{a_n - \Phi}. \quad (9)$$

To obtain the distribution function $h_n(g)$ of the occupied channels, we first note that Eq.(5) implies that g

is dominated by the minimum inter-sphere conductance $\sigma_{\min}$ among the set of n conductances in series. Hence the small- g limit of $h_n(g)$ is just the distribution function $\tilde{f}$ of $\sigma_{\min}$:

$$\tilde{f}(\sigma_{\min}) = n f(\sigma_{\min}) \left[1 - \int_{\sigma_{\min}}^1 d\sigma_{\min} f(\sigma_{\min}) \right]^{n-1}, \quad (10)$$

which, from Eq.(8) and by setting $g \simeq \sigma_{\min}$, leads to:

$$\lim_{g \rightarrow 0} h_n(g) \simeq n(1 - \alpha_n) g^{-\alpha_n}. \quad (11)$$

The conducting bond distribution function behaves therefore as Eq.(3) so that for $\alpha_n > \alpha_c \simeq 0.107$ transport universality breaks down and $t > t_0$. For $L = 1 \mu\text{m}$, $\Phi = 10 \text{ nm}$, and $\xi = 1 \text{ nm}$ this is achieved already for $n < 90$, i. e., slightly less than the maximum number $L/\Phi = 100$ of spheres which can be accommodated inside a channel.

Our model of universality breakdown in TFRs can be readily generalized to describe more realistic situations. For example, the number n of spheres inside the occupied channels can vary according to a given distribution. It is also straightforward to rewrite Eq.(7) in order to describe cases in which the diameter Φ of the spheres is not fixed,²² or to let the size of the insulating grains to change by assigning a distribution function for L . It is then possible to have different scenarios and, more importantly, to obtain a crossover from transport universality ($t = t_0$) to nonuniversality ($t > t_0$) within the same framework. This reminds the experimental situation reported for TFRs and summarized in Fig.1.

Let us now comment on the capability of other existing theories to describe transport universality breakdown in TFRs. At a first glance, the swiss-cheese model of Ref. 19 is a natural candidate since the large values of L/Φ typical of many TFRs may lead to an effective continuous conducting phase filling the voids between the large glassy grains. However, there are examples in which nonuniversality has been reported for TFRs with L/Φ only of order $\sim 5 - 10$,⁵ a value probably too small to be compatible with the swiss-cheese picture. Even more problematic are the cases for which $t = t_0 \simeq 2.0$ has been measured for TFRs with $L/\Phi \sim 100$ (see for example Fig.1), while the swiss-cheese model would have predicted $t > t_0$. Regarding instead the model proposed by Balberg,²⁰ for which transport is dominated by random tunneling processes in a percolating network, it is important to point out that it was defined by using a phenomenological distribution function for the nearest-neighbour particle distances very similar to our Eq.(7). Balberg argued that such form of $P(r)$ is a reasonable compromise between the distribution function of spheres randomly placed in three dimensions,²¹ and the effect of interactions between the conducting and insulating phases. Instead we have shown that Eq.(7), and consequently the power-law divergence of $h(g)$, is a straightforward outcome of the quasi one-dimensional

geometry of the conducting channels in the segregation model of TFRs. Despite that our model has been formulated specifically for TRFs, nevertheless it could be applied also to other segregated disordered compounds for which tunneling is the main mechanism of transport and nonuniversality has been reported.¹⁶

In conclusion, we have proposed a simple tunneling-percolation model capable of describing the observed transport universality breakdown in TFRs. Essential ingredients of the theory are the segregated structure, modelled by quasi-one dimensional channels occupied randomly by the conducting particles, and intergrain tunneling taking place within the channels.

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